CMOS Digital Integrated Circuits Silicon Monolithic

74VHCV374FT

1. Functional Description

· Octal Schmitt D-Type Flip-Flop with 3-State Outputs

2. General

The 74VHCV374FT is an advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input ($\overline{\text{OE}}$).

When the OE input is high, the eight outputs are in a high impedance state.

Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the 74VHCV374FT are capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity. Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

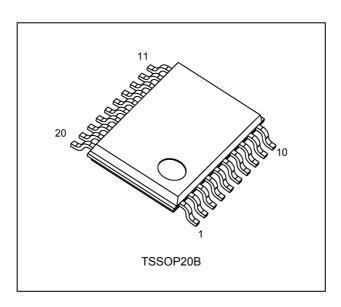
3. Features

(1) AEC-Q100 (Rev. H) (Note 1)

representative.

- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: $f_{MAX} = 185 \text{ MHz}$ (typ.) at $V_{CC} = 5.0 \text{ V}$
- (4) Low power dissipation: $I_{CC} = 2.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (5) Wide operating voltage range: $V_{CC(opr)} = 1.8 \text{ V}$ to 5.5 V
- (6) Output current: $|I_{OH}|/I_{OL} = 16 \text{ mA (min)}(V_{CC} = 4.5 \text{ V})$
- (7) Power-down protection is provided on all inputs and outputs.
- (8) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 374 type. Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales

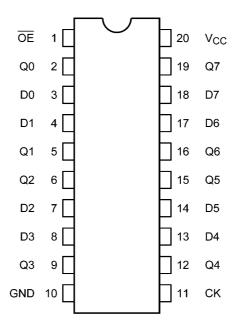
4. Packaging



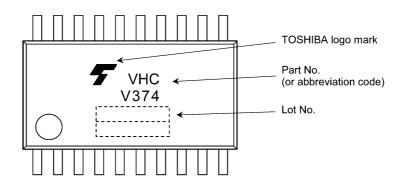
Start of commercial production



5. Pin Assignment



6. Marking



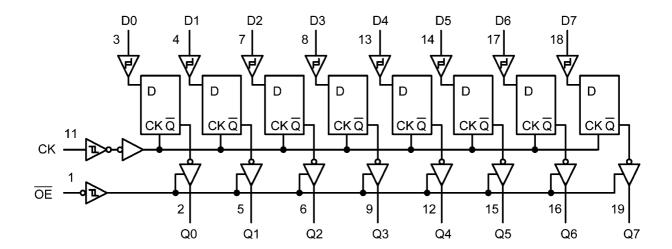
7. Truth Table

	Inputs	Output	
ŌĒ	СК	D	Output
Н	Х	Х	Z
L		Х	Qn
L		L	L
L		Н	Н

X: Don't careZ: High impedanceQn: No change



8. System Diagram





9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-50	mA
Output diode current	I _{OK}	(Note 3)	±50	mA
Output current	I _{OUT}		±50	mA
Power dissipation	P _D	(Note 4)	180	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state. IOUT absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Note 4: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Note	Rating	Unit
Supply voltage	V _{CC}	_		1.8 to 5.5	V
Input voltage	V _{IN}	_		0 to 5.5	V
Output voltage	V _{OUT}	_	(Note 1)	0 to 5.5	V
			(Note 2)	0 to V _{CC}	
Operating temperature	T _{opr}	_		-40 to 125	°C
Input rise and fall times	dt/dv	V_{CC} = 3.3 ± 0.3 V		0 to 20	ms/V
		V_{CC} = 5.0 ± 0.5 V		0 to 1	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition	n	V _{CC} (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V _P	_		1.8	_	_	1.65	V
				2.3	_	_	1.85	
				3.0	_	_	2.20	
				4.5	_	_	3.15	
				5.5	_	_	3.85	
Negative threshold voltage	V _N	_		1.8	0.15	_		V
				2.3	0.45	_	_	
				3.0	0.90	_	_	
				4.5	1.35	_	_	
					1.65	_	_	
Hysteresis voltage	V _H	_		1.8	0.15	_	1.05	V
				2.3	0.20	_	1.10	
				3.0	0.30	_	1.20	
				4.5	0.40	_	1.40	
				5.5	0.50	_	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	1.8	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I _{OH} = -8 mA	3.0	2.58	_	_	
			I _{OH} = -16 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I_{OL} = 50 μ A	1.8	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 8 mA	3.0	_	_	0.36	
			I _{OL} = 16 mA	4.5	_	_	0.44	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.8 to 5.5	_	_	±0.5	μА
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0			0.5	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	2.0	μА



11.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_		1.8	_	1.65	V
				2.3	_	1.85	
				3.0	_	2.20	
				4.5	_	3.15	
				5.5	_	3.85	
Negative threshold voltage	V _N	_		1.8	0.15	_	V
				2.3	0.45	_	
				3.0	0.90	_	
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V _H	_		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I _{OH} = -8 mA	3.0	2.48	_	
			I _{OH} = -16 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	1.8	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 8 mA	3.0	_	0.44	
			I _{OL} = 16 mA	4.5	_	0.55	
3-state output OFF-state leakage current	l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.8 to 5.5	_	±5.0	μА
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0		5.0	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	20.0	μА



11.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_		1.8	_	1.65	V
				2.3	_	1.85	
				3.0	_	2.20	
				4.5	_	3.15	
				5.5	_	3.85	
Negative threshold voltage	V _N	_		1.8	0.15	_	V
				2.3	0.45	_	
				3.0	0.90	_	
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V _H	_		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I _{OH} = -8 mA	3.0	2.40	_	
			I _{OH} = -16 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	1.8	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 8 mA	3.0	_	0.55	
			I _{OL} = 16 mA	4.5	_	0.65	
3-state output OFF-state leakage current	l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.8 to 5.5	_	±20.0	μА
Power-OFF leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0		20.0	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±2.0	μА
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	40.0	μА



11.4. Timing Requirements (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Symbol	V _{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	2.5 ± 0.2	6.0	ns
		3.3 ± 0.3	5.0	
		5.0 ± 0.5	5.0	
Minimum setup time	ts	2.5 ± 0.2	5.0	ns
		3.3 ± 0.3	4.5	
		5.0 ± 0.5	3.0	
Minimum hold time	t _h	2.5 ± 0.2	2.5	ns
		3.3 ± 0.3	2.0	
		5.0 ± 0.5	2.0]

11.5. Timing Requirements (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	V _{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	2.5 ± 0.2	7.0	ns
		3.3 ± 0.3	5.5	
		5.0 ± 0.5	5.0	
Minimum setup time	ts	2.5 ± 0.2	5.5	ns
		3.3 ± 0.3	4.5	
		5.0 ± 0.5	3.0	
Minimum hold time	t _h	2.5 ± 0.2	2.5	ns
		3.3 ± 0.3	2.0	
		5.0 ± 0.5	2.0	

11.6. Timing Requirements (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	V _{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	2.5 ± 0.2	7.0	ns
		3.3 ± 0.3	5.5	
		5.0 ± 0.5	5.0	
Minimum setup time	ts	2.5 ± 0.2	6.0	ns
		3.3 ± 0.3	4.5	
		5.0 ± 0.5	3.0	
Minimum hold time	t _h	2.5 ± 0.2	2.5	ns
		3.3 ± 0.3	2.0	
		5.0 ± 0.5	2.0	



11.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		_	2.5 ± 0.2	15	_	12.1	16.3	ns
(CK-Q)					50	_	14.9	19.3	
				3.3 ± 0.3	15	_	7.1	12.7	
					50	_	9.2	16.2	
				5.0 ± 0.5	15	_	5.4	8.1	
					50	_	7.1	10.1	
3-state output enable time	t _{PZL} ,t _{PZH}		R _L = 1 kΩ	2.5 ± 0.2	15	_	9.4	15.9	ns
					50	_	12.3	18.8	
				3.3 ± 0.3	15	_	6.5	11.0	
					50	_	8.7	14.5	
				5.0 ± 0.5	15	_	4.5	7.6	
					50	_	6.2	9.6	
3-state output disable time	t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	_	14.5	17.3	ns
				3.3 ± 0.3	50	_	10.9	14.0	
				5.0 ± 0.5	50	_	8.0	8.8	
Maximum clock frequency	f _{MAX}		_	2.5 ± 0.2	15	60	80	_	MHz
					50	50	65	_	
				3.3 ± 0.3	15	80	140	_	
					50	55	105	_	
				5.0 ± 0.5	15	130	185	_	
					50	85	140	_	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	2.5 ± 0.2	50	_	_	2.0	ns
				3.3 ± 0.3	50	_	_	1.5	
				5.0 ± 0.5	50	_	_	1.0	
Input capacitance	C _{IN}		_			_	4	10	pF
Output capacitance	C _{OUT}		_			_	6		pF
Power dissipation capacitance	C _{PD}	(Note 2)					21		pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per latch)

And the total C_{PD} when n pcs. of latch operate can be gained by the following equation.

 C_{PD} (total) = 11 + 10 × n

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.



11.8. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_f = t_f = 3 ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		_	2.5 ± 0.2	15	1.0	19.0	ns
(CK-Q)					50	1.0	23.0	
				3.3 ± 0.3	15	1.0	15.0	
					50	1.0	18.5	
				5.0 ± 0.5	15	1.0	9.5	
					50	1.0	11.5	
3-state output enable time	-state output enable time t_{PZL}, t_{PZH} $R_L = 1 \text{ k}\Omega$ 2	2.5 ± 0.2	15	1.0	19.0	ns		
					50	1.0	22.0	
				3.3 ± 0.3	15	1.0	13.0	
					50	1.0	16.5	
				5.0 ± 0.5	15	1.0	9.0	
					50	1.0	11.0	
3-state output disable time	t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	1.0	19.0	ns
				3.3 ± 0.3	50	1.0	16.0	
				5.0 ± 0.5	50	1.0	10.0	
Maximum clock frequency	f _{MAX}		_	2.5 ± 0.2	15	50	_	MHz
					50	40	_	
				3.3 ± 0.3	15	70	_	
					50	50	_	
				5.0 ± 0.5	15	110	_	
					50	75	_	
Output skew	t_{osLH}, t_{osHL}	(Note 1)	_	2.5 ± 0.2	50	_	2.0	ns
				3.3 ± 0.3	50	_	1.5	
				5.0 ± 0.5	50	_	1.0	
Input capacitance	C _{IN}						10	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$



11.9. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		_	2.5 ± 0.2	15	1.0	21.0	ns
(CK-Q)					50	1.0	25.5	
				3.3 ± 0.3	15	1.0	17.0	
					50	1.0	20.5	
				5.0 ± 0.5	15	1.0	11.0	
					50	1.0	13.0	
3-state output enable time	t_{PZL}, t_{PZH}		R _L = 1 kΩ	2.5 ± 0.2	15	1.0	21.5	ns
					50	1.0	24.5	
				3.3 ± 0.3	15	1.0	15.0	
					50	1.0	18.5	
				5.0 ± 0.5	15	1.0	10.0	
					50	1.0	12.0	
3-state output disable time	t_{PLZ}, t_{PHZ}		R _L = 1 kΩ	2.5 ± 0.2	50	1.0	20.5	ns
				3.3 ± 0.3	50	1.0	17.5	
				5.0 ± 0.5	50	1.0	11.0	
Maximum clock frequency	f _{MAX}		_	2.5 ± 0.2	15	40.0	_	MHz
					50	30.0	_	
				3.3 ± 0.3	15	60.0	_	
					50	40.0	_	
				5.0 ± 0.5	15	100.0	_	
					50	65.0	_	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	2.5 ± 0.2	50		2.0	ns
				3.3 ± 0.3	50		1.5	
				5.0 ± 0.5	50		1.0	
Input capacitance	C _{IN}					_	10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

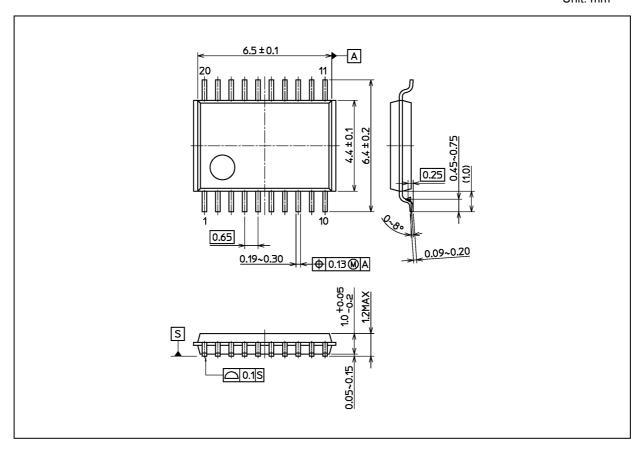
11.10. Noise Characteristics (Unless otherwise specified, T_a = 25 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Max	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	3.3	0.3	_	V
			5.0	0.7	_	
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	3.3	-0.1	_	V
			5.0	-0.4	_	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low-level dynamic input voltage	V_{ILD}	C _L = 50 pF	5.0	1	1.5	V



Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	



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